Two pseudogaps with different energy scales at the antinode of the high-temperature Bi$_2$Sr$_2$CuO$_6$ superconductor using angle-resolved photoemission spectroscopy

K. Nakayama,1 T. Sato,1 Y.-M. Xu,2,4 Z.-H. Pan,2,1 P. Richard,3,4 H. Ding,2,4 H.-H. Wen,4,1 K. Kudo,5,† T. Sasaki,5
N. Kobayashi,3 and T. Takahashi1,3

1Department of Physics, Tohoku University, Sendai 980-8578, Japan
2Department of Physics, Boston College, Chestnut Hill, Massachusetts 02467, USA
3World Premier International Research Center, Advanced Institute for Materials Research, Tohoku University, Sendai 980-8577, Japan
4Beijing National Laboratory for Condensed Matter Physics, and Institute of Physics, Chinese Academy of Sciences, Beijing 100190, China
5Institute for Materials Research, Tohoku University, Sendai 980-8577, Japan

(Received 26 May 2011; published 23 June 2011)

We performed high-resolution angle-resolved photoemission spectroscopy on single-layered cuprate Bi$_2$Sr$_2$CuO$_6$, to clarify the origin of the pseudogap. By using various photon energies, we succeeded in directly observing two different pseudogaps with two different energy scales which coexist in the antinodal region: one reflects the $d_{x^2-y^2}$-wave pairing strength while the other has a larger energy scale suggesting an origin distinct from superconductivity. The observed two-pseudogap behavior provides a key to fully understanding the pseudogap phenomena in cuprates.

DOI: 10.1103/PhysRevB.83.224509 PACS number(s): 74.25.Jb, 74.20.Mn, 74.72.-h, 79.60.—i

I. INTRODUCTION

The pseudogap observed in the excitation spectrum as a suppression of spectral weight in the normal state of cuprate superconductors has attracted much attention since it is closely related to the mechanism of high-$T_c$ (transition temperature) superconductivity. The opening of the pseudogap has been interpreted either as a precursor of Cooper pairing above $T_c$ without phase coherence or as the development of some sort of ordered state which competes with superconductivity. However, in spite of intensive studies, the origin of the pseudogap is still highly controversial. This is largely due to the lack of consensus on the energy scale of the pseudogap. Some experiments pointed out that the pseudogap has a different energy scale from that of the superconducting (SC) gap, indicative of the presence of two energy scales (possibly two distinct energy gaps) in the SC state. This two-gap behavior suggests that the pseudogap has a competing nature and is not directly related to superconductivity. It has been reported that the two-gap behavior is pronounced in low-$T_c$ systems such as Bi$_2$Sr$_2$CaCu$_2$O$_8$ (Bi2212), single-layered Bi$_2$Sr$_2$CuO$_6$ (Bi2201), and La$_{2-x}$Sr$_x$CuO$_4$ (LSCO). On the other hand, even in the low-$T_c$ systems, there are some recent experimental studies reporting the presence of a single energy scale where the SC gap below $T_c$ and the pseudogap above $T_c$ show an identical energy scale with no evidence for the two-gap behavior, strongly supporting a pairing origin of the pseudogap. The apparent contradiction requires further experimental investigation on the energy scale of the pseudogap in low-$T_c$ cuprates to elucidate the origin of the pseudogap.

In this paper, we report high-resolution angle-resolved photoemission spectroscopy (ARPES) results on single-layered cuprate Bi2201. By comparing ARPES data obtained with two different photon energies (8.437 and 21.218 eV), we clearly observe two energy scales at the antinode below $T_c$. We demonstrate that these energy scales persist even above $T_c$, suggesting the presence of two different types of pseudogaps coexisting in the same momentum ($k$) region. We discuss the implications of the present experimental results in relation to the existing models as well as the origin of the pseudogap.

II. EXPERIMENTS

High-quality single crystals of slightly overdoped (Bi,Pb)$_2$Sr$_2$CuO$_{6+x}$ (Pb-Bi2201; $T_c \approx 21$ K) and nearly optimally doped Bi$_2$Sr$_1.5$La$_{0.5}$CuO$_{6+x}$ (La-Bi2201; $T_c \approx 32$ K) were grown by the floating-zone and the traveling-solvent floating-zone methods, respectively. High-resolution ARPES measurements were performed using VG-SCIENTA SES2002 and MBS A1 photoemission spectrometers with xenon (Xe) and helium (He) plasma discharge lamps. We used one of the Xe-I lines ($h\nu = 8.437$ eV) and the He-Ia line (21.218 eV) to excite photoelectrons. The angular resolution was set at 2–4 and 6–12 meV for the measurements with the Xe and He lamps, respectively. The angular resolution was set at 0.2°. We cleaved samples under ultrahigh vacuum better than $4 \times 10^{-11}$ Torr to obtain a clean and fresh sample surface for ARPES measurements. The Fermi level ($E_F$) of samples was referenced to that of a gold film evaporated onto the sample holder.

III. RESULTS AND DISCUSSION

First we present ARPES data in the SC state. Figures 1(a) and 1(b) show the ARPES intensity plot at $E_F$ of Pb-Bi2201 as a function of the two-dimensional wave vector measured with the Xe-I and He-Ia lines, respectively. While the ARPES intensity distribution in the $k$ space is different between these plots likely due to matrix-element effects, we find a nearly identical Fermi-surface shape (red curve) centered at the ($\pi$, $\pi$) point as determined by tracing the Fermi wave vector ($k_F$) points. In the SC state, both the Xe-I and He-Ia spectra commonly show a holelike band crossing $E_F$ in the nodal region [Figs. 1(c) and 1(d)] and a clear leading-edge shift toward higher binding energy in the antinodal region [Figs. 1(e) and 1(f)]. Although these experimental results
suggest the similarity of the basic electronic structure between the He-Ix and Xe-I spectra, a closer look further reveals marked differences in the gap behavior.

Figures 2(a) and 2(b) display symmetrized ARPES spectra of Pb-Bi2201 measured at kF points with various Fermi-surface angles φ at 10 K (below Tc) with the Xe-I and He-Ix lines, respectively. The gap size, defined by the energy separation between the peak position and E_F, monotonically increases on going from the nodal (bottom in the panel) to the antinodal (top) regions, which is consistent with the anisotropic gap opening in the SC state. As also visible in Fig. 2(d), there is a striking difference between the He- and Xe-spectra on the peak position around the antinode, i.e., the peak in the He spectrum is located at much higher binding energy than that of the Xe spectrum (18.5 and 11.5 meV, respectively). We use ΔXe and ΔHe to note the gap size obtained from the Xe and He spectra, respectively. In Fig. 2(e), we plot estimated ΔXe and ΔHe at 10 K at various kF points. The k dependence of ΔXe is well fitted by the d_iσ−d_jσ-wave gap function with a small admixture of a higher-order component, representing the energy scale of the SC gap. Although ΔHe shows a quantitative agreement with ΔXe near the node, it gradually deviates from ΔXe with approaching the antinode. A similar trend is also observed in La-Bi2201, whose Tc value (32 K) is much higher than Pb-Bi2201 (21 K). As shown in Fig. 2(f), the difference between ΔXe and ΔHe (arrow vs dashed line) exceeds 20 meV at the antinode, whereas ΔXe and ΔHe appear identical near the node. As visible in Fig. 2(g), the observed significant deviation of ΔHe from the ideal d_iσ−d_jσ-wave gap function appears similar to previous ARPES results which have been interpreted with two types of energy gaps in different k regions, i.e., (i) the SC gap which dominates the gap symmetry near the node, and (ii) the large gap which develops near the antinode. The good agreement between ΔHe and ΔXe near the node in the present ARPES result is consistent with the pairing nature of the gap around the node in the He spectra. In addition, the marked difference between ΔHe and ΔXe near the antinode provides a direct evidence for the presence of two energy gaps below Tc (a small gap and a large gap) even in the same k region, although we cannot completely rule out a possible k dependence of the gap size to account for the difference between ΔHe and ΔXe. This observation should be strictly distinguished...
from previous works reporting the "two gaps" phenomenon in the sense that two gaps appear simultaneously at the antinodal region.

To clarify how these gaps evolve into the pseudogap above $T_c$, we have performed ARPES measurements at 24 K (just above $T_c$) on Pb-Bi2201 with the Xe-I and He-Ia lines. As seen in both sets of data in Fig. 3(a), the symmetrized spectrum near the node shows a single peak at $E_F$, while the spectrum at the antinode exhibits spectral weight suppression in the vicinity of $E_F$, a signature of the pseudogap opening [Fig. 3(b)]. In the antinodal region, the characteristic energy scales of the pseudogap are $\sim 12$ and $\sim 20$ meV for the Xe and He spectrum, respectively, which are similar to the values of $\Delta_{Xe}$ and $\Delta_{He}$ below $T_c$ in the antinodal region, as shown in Fig. 3(c). It is thus inferred that there exist two pseudogaps above $T_c$ with precursor-pairing and unknown origin which smoothly evolve from the $d_{x^2-y^2}$-wave SC gap and the larger gap below $T_c$, respectively. It is emphasized that, although a few previous ARPES results suggested a two-pseudogap-like behavior,22,23 the present ARPES result directly demonstrates the existence of two energy scales at the antinode.

The present observation solves the contradiction among recent ARPES experiments. While some studies supported the pairing origin of the pseudogap,12-16 others pointed out that the pseudogap is not directly related to the pairing.6-9 Such difference is naturally understood by taking into account the presence of two pseudogaps. Namely, the former studies detected only the small gap and the latter observed mostly the large gap, essentially because of the difference in the experimental conditions such as the photon energy. In fact, the previously reported pseudogap values of $\sim 15$ meV13,15 and $\sim 35$ meV12,14 for La-Bi2201 (which differ among different groups) agree well with the maximum values of $\Delta_{Xe}$ and $\Delta_{He}$, respectively. In addition, the difference of the gap anisotropy in the pseudogap phase of La$_{1.875}$Ba$_{0.125}$CuO$_4$22,24 can also be explained within the two-pseudogap picture.

Finally, we discuss the implication of the observed photon-energy dependence. We revealed that the measurements using the Xe-I ($h\nu = 8.437$ eV) and the He-Ia ($21.218$ eV) lines are sensitive to the small gap and the large gap, respectively. One explanation of such behavior is that the two different gaps suffer different matrix-element effects during the photoexcitation process and they can be selectively observed by specific conditions of the photon energy. This explanation may be valid if there are two different bands producing the small and the large gaps, since the bilayer-split bands in Bi2212 obey different matrix elements.25 On the other hand, Bi2201 is a single-layered system and there would be a single band near $E_F$. In this case, the appearance of two energy scales on the single coherent quasiparticle band may be explained by the idea that the large gap is not a complete gap but rather a soft gap, and the remaining density of states within the large gap contributes to the formation of the small gap. It is also possible to attribute the large and the small gaps to the incoherent and the coherent parts of the spectral function. In either case, the two gaps basically arise from a single-band spectral function and their intensity ratio would not depend on the photon energy. Hence we think that the present observation may not be simply explained by the matrix-element effect. Another explanation is that the difference between the He and Xe spectra originates from the surface and/or bulk sensitivity. In this case, it is inferred that the large gap, which seems not directly related to the superconductivity, is either (i) an extrinsic feature stabilized at the surface or (ii) an intrinsic feature in bulk with much pronounced influence at the surface. On the other hand, the small gap, which is closely related to the pairing, would reflect bulk properties because electrons excited with the Xe-I line have a relatively long escape depth (20–40 Å) as compared to that excited with the He-Ia line (5–10 Å).20 The bulk nature of the small gap is also supported by a basic agreement between $\Delta_{Xe}$ in La-Bi2201 ($\sim 14$ meV) and an energy scale observed in the $B_{1g}$ Raman spectrum ($\sim 17$ meV).26 While most of previous results on Bi220112,13,15,16,23 agree with the expectation that the spectral weight related to the small gap feature is enhanced as the photon energy is lowered (i.e., the photoelectron escape depth becomes longer), there is one exceptional result which shows the small gap feature at the antinode even with $h\nu = 22.5$ eV in optimally doped La-Bi2201 with a zero residual resistivity.13 Since the authors reported that the small gap disappears in another optimally doped sample with a finite residual resistivity,13 the disorder effect may be an essential ingredient in suppressing the small gap component and also in causing the difference in the electronic states between surface and bulk. In any cases, the pairing interaction is essential in realizing the origin of the pseudogap, and we conclude that the scenario assuming the opening of a single competing pseudogap is insufficient for the correct understanding of the pseudogap phenomena in cuprates.

**IV. CONCLUSION**

In conclusion, we performed a high-resolution ARPES study of Bi2201 by using the Xe and He discharge lamps. The result clearly shows the presence of two energy scales in the antinodal region below and above $T_c$, indicating the existence of two different pseudogaps. We have concluded that...
the smaller pseudogap originates from the precursor pairing above $T_c$, while the larger pseudogap is not directly related to the superconductivity. The present findings put a strong constraint in modeling the pseudogap phenomena of cuprates.

ACKNOWLEDGMENTS

This work was supported by grants from JST-CREST, JSPS, MEXT of Japan, NSF of US, and MOST of China.

\footnote{Present address: Materials Sciences Division, Lawrence Berkeley National Laboratory, Berkeley, CA 94720, USA.}

\footnote{Present address: Condensed Matter Physics and Materials Science Department, Brookhaven National Lab, Upton, NY 11973, USA.}

\footnote{Present address: National Laboratory of Solid State Microstructures and Department of Physics, Nanjing University, Nanjing 210093, China.}

\footnote{Present address: Department of Physics, Okayama University, Okayama 700-8530, Japan.}


